Vishay Semiconductors

Ultrafast Rectifier, 2 x 15 A FRED Pt[®]



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PRODUCT SUMMARY					
Package	TO-263AC (SMPD)				
I _{F(AV)}	2 x 15 A				
V _R	600 V				
V _F at I _F	0.9 V				
t _{rr}	55 ns				
T _J max.	175 °C				
Diode variation	Dual die				

FEATURES

- Ultrafast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V _{RRM}		600	V		
Average rectified forward current per device	per device		T _ 142 °C	30			
	per diode	IF(AV)	T _{solder pad} = 143 °C	15			
Non-repetitive peak surge current	per device		$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	300	A		
	per diode	IFSM		160			

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage, per diode	¥-	I _F = 15 A	-	1.03	1.25	V
Forward voltage, per diode V _F	۷F	I _F = 15 A, T _J = 150 °C	-	0.9	1.1	
Deverse leekens eurrent per diede		$V_{R} = V_{R}$ rated	-	-	15	
Reverse leakage current, per diode	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	70	300	μA
Junction capacitance, per diode	C _T	V _R = 600 V	-	13	-	pF

Revision: 10-Feb-15 1 Document Number: 95823 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



ROHS COMPLIANT HALOGEN

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V _R = 30 V	-	55	-	
Reverse recovery time	+	$I_{F} = 0.5 \text{ A}, I_{R} = 1 \text{ A}, I_{rr}$	= 0.25 A	-	-	65	ns
Reverse recovery time	t _{rr}	T _J = 25 °C		-	96	-	
		T _J = 125 °C		-	150	-	
Deck receiver a surrent		T _J = 25 °C	l _F = 15 A, dl _F /dt = 500 A/µs, V _R = 400 V	-	18	-	^
Peak recovery current	I _{RRM}	T _J = 125 °C		-	26	-	A
Reverse recovery charge Q _{rr}	0	T _J = 25 °C]	-	1.0	-	
	Q _{rr}	T _J = 125 °C		-	2.0	-	μC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, per diode junction to solder pad	R _{thJ-Sp}		-	1.2	1.7	°C/W
Approximate weight				0.55		g
				0.02		oz.
Marking device		Case style TO-263AC (SMPD)		30CI	DU06	

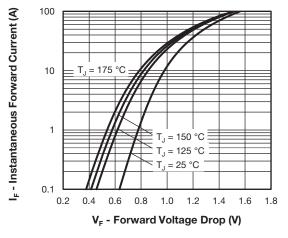


Fig. 1 - Typical Forward Voltage Drop Characteristics

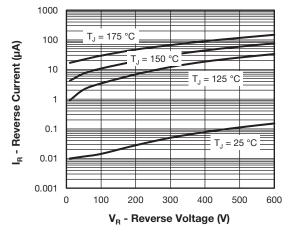


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-30CDU06HM3

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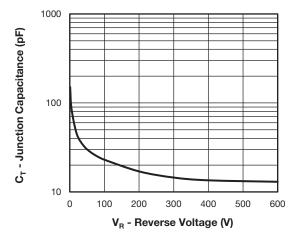


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

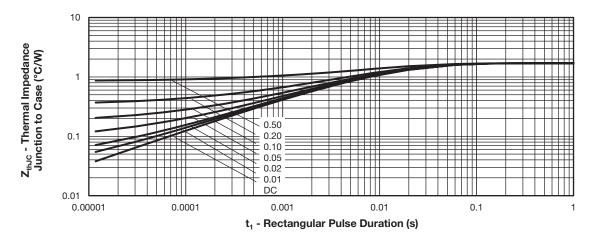
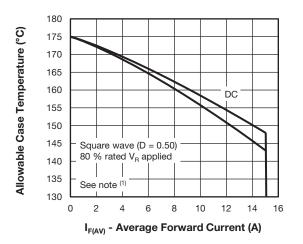
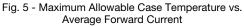


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V_{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

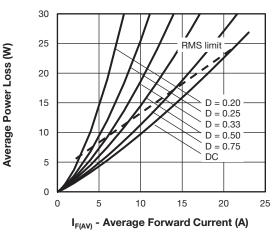


Fig. 6 - Forward Power Loss Characteristics

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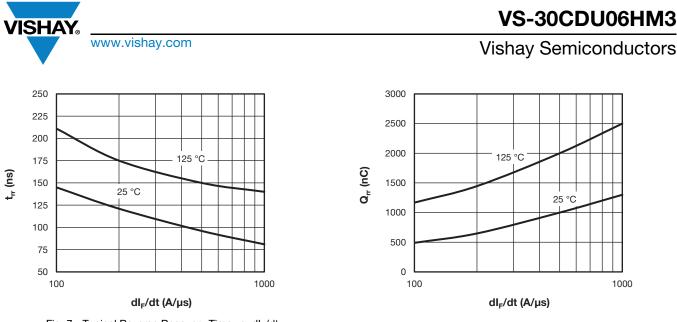


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt



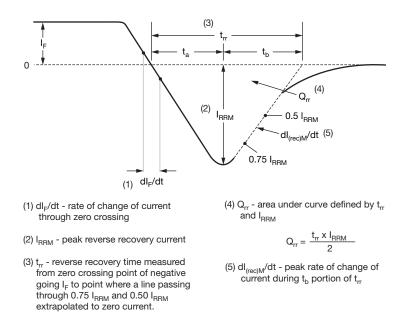


Fig. 9 - Reverse Recovery Waveform and Definitions

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SHAY

Device code	VS-	30	с	D	U	06	н	М3
	1	2	3	4	5	6	7	8
			•	nicondu ing (30 A	•	oduct		
	3			figuratio on catho				
	H		SMPD cess typ	packag	e			
				st recove	ery			
	7	- H=	AEC-Q	de (06 = 101 qua	alified			
	8	- M3	= halog	en-free,	RoHS-	complia	ant, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	REFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-30CDU06HM3/I	2000	2000	13" diameter plastic tape and reel				

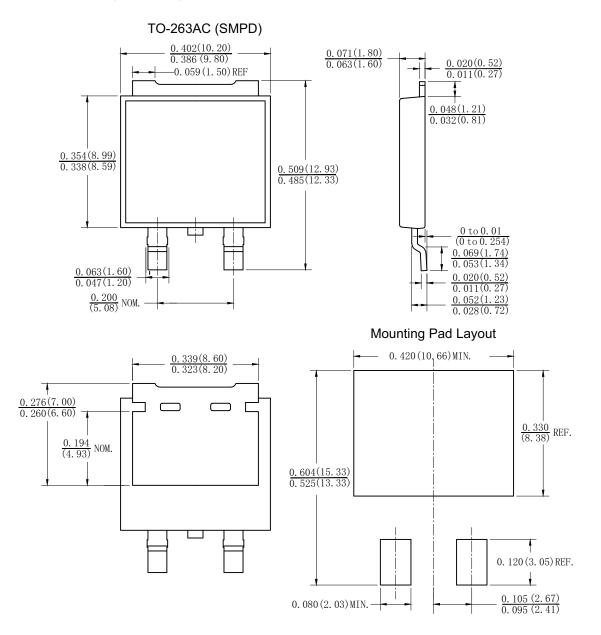
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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